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2000
09/08/00
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Class	Subclass	ISSUE CLASSIFICATION



PATENT NUMBER

U.S. UTILITY Patent Application

CLASS NO. Q20	PATENT DATE
CLASS NO. 1R	

APPLICATION NO. 09/827676	CONT/PRIOR F	CLASS 267	SUBCLASS 059	ART UNIT 2817	EXAMINER QUICK
APPLICANTS Masahito Fujino Hisao Hayashi					
TITLE Thin-film transistor and method for making the same					
PTO-2040 12/89					

ISSUING CLASSIFICATION			
ORIGINAL	CROSS REFERENCE		
CLASS	SUBCLASS	CLASS	SUBCLASS
INTERNATIONAL CLASSIFICATION			

<input type="checkbox"/> The term of this patent is equivalent to _____ (year) has been determined.	Priority Date	Priority Number	Priority Country
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent No. _____	Priority Date	Priority Number	Priority Country
<input type="checkbox"/> The period _____ months of this patent have been determined.	Priority Date	Priority Number	Priority Country

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